C	Reg. No.:				
	Question Paper Code: 52408A				
	B.E. / B.Tech. DEGREE EXAMINATION, MAY 2024				

## Second Semester

		Secon	d Semester	
	]	Electronics and Con	nmunication Engineering	
		15UEC208 - ELE	CTRONIC DEVICES	
		(Regul	ation 2015)	
Dur	ation: Three hours			Maximum: 100 Marks
		Answer A	ALL Questions	
		PART A - (	$5 \times 1 = 5 \text{ Marks}$	
1.	The forbidden energy	CO1- R		
	(a) 0.12 eV	(b) 0.32 eV	(c) 0.72 eV	(d) 0.92 eV
2.	The diode is a			CO2- R
	(a) is the simplest of s	semiconductor devic	ees	
	(b) has characteristics	that closely match	those of a simple switch	
	(c) is a two-terminal d	levice		
	(d) All of the above			
3.	Most of the electrons	CO3- R		
	(a) into the collector		(b) into the emitter	
	(c) in to the base supp	ply	(d) out of base lead	
4.	For a JFET, the value is the	of VDS at which II	D becomes essentially con	nstant CO4- R
	(a) pinch-off voltage	(b) cutoff voltage	(c) breakdown voltage	(d) ohmic voltage
5.	A Diac is switch			CO5- R
	(a) An A.C	(b) D.C	(c) Either of the above	(d) None of the above

## $PART - B (5 \times 3 = 15 \text{ Marks})$

6	State Mass Action Law.									
7.	Defin	(	CO2- R							
8.	Defin	(	CO3- R							
9.	Defin	(	CO4- R							
10.	What is SCR? Mention its Applications.			CO5- R						
	PART – C (5 x 16= 80Marks)									
11.	(a)	Explain the Classifications of semiconductors and derive the expression for carrier concentration in intrinsic semiconductor.  Or	CO1- U	(16)						
	(b)	Explain about drift and diffusion currents and obtain its expression.	CO1- U	(16)						
12.	(a)	<ul><li>(i) Give diode current equation</li><li>(ii) Explain how a barrier potential is developed at the PN Junction.</li></ul>	CO2- U CO2- U	(8) (8)						
		Or Or								
	(b)	Explain the construction and working of full-wave rectifiers and its parameter	CO2- U	(16)						
13.	(a)	Explain CE Transistor configuration and draw a circuits for determining input and output characteristics.  Or	CO3- U	(16)						
	(b)	A transistor with IB=100 $\mu$ A and IC=2mA Find (i) B of the transistor (ii) $\alpha$ of the transistor (iii) emitter current I <sub>E</sub>	CO3- U	(16)						
14.	(a)	Explain the construction and operation of N Channel JFET.  Or	CO4- U	(16)						
	(b)	Explain the principle of operation of enhancement N-channel MOSFET and draw its drain characteristics.	CO4- U	(16)						

15. (a) Explain the principle behind the tunnel diode and varactor diode CO5- U (16)

Or

(b) Draw the characteristics of UJT and explain its working CO5- U (16) principle..